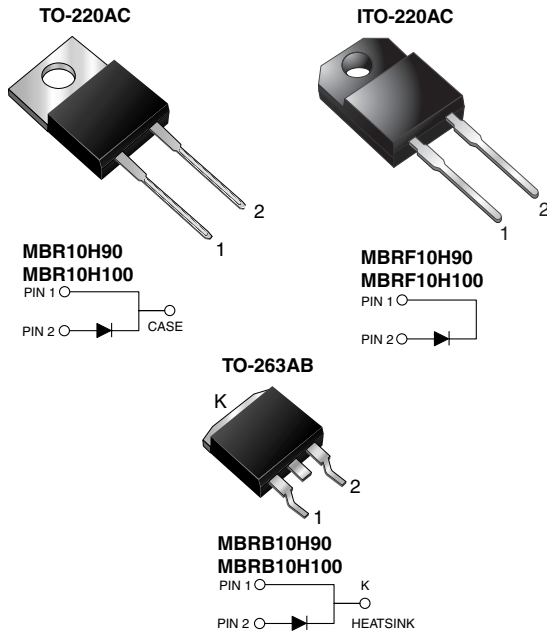


## High-Voltage Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



### FEATURES

- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AC and ITO-220AC package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



**RoHS**  
COMPLIANT

### TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

### MECHANICAL DATA

**Case:** TO-220AC, ITO-220AC, TO-263AB

Epoxy meets UL 94V-0 flammability rating

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs maximum

### PRIMARY CHARACTERISTICS

$I_{F(AV)}$	10 A
$V_{RRM}$	90 V, 100 V
$I_{FSM}$	250 A
$V_F$	0.64 V
$I_R$	4.5 $\mu$ A
$T_J$ max.	175 °C

### MAXIMUM RATINGS ( $T_C = 25$ °C unless otherwise noted)

PARAMETER	SYMBOL	MBR10H90	MBR10H100	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	90	100	V
Working peak reverse voltage	$V_{RWM}$	90	100	V
Maximum DC blocking voltage	$V_{DC}$	90	100	V
Maximum average forward rectified current	$I_{F(AV)}$	10		A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	$I_{FSM}$	250		A
Peak repetitive reverse current at $t_p = 2$ $\mu$ s, 1 kHz	$I_{RRM}$	0.5		A
Voltage rate of change (rated $V_R$ )	dV/dt	10 000		V/ $\mu$ s
Operating junction and storage temperature range	$T_J, T_{STG}$	- 65 to + 175		°C
Isolation voltage (ITO-220AC only) from terminal to heatsink $t = 1$ min	$V_{AC}$	1500		V

# MBR(F,B)10H90 & MBR(F,B)10H100

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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)					
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT
Maximum instantaneous forward voltage <sup>(1)</sup>	$I_F = 10\text{ A}$	$T_C = 25\text{ }^\circ\text{C}$	$V_F$	0.77	V
	$I_F = 10\text{ A}$	$T_C = 125\text{ }^\circ\text{C}$		0.64	
	$I_F = 20\text{ A}$	$T_C = 25\text{ }^\circ\text{C}$		0.88	
	$I_F = 20\text{ A}$	$T_C = 125\text{ }^\circ\text{C}$		0.73	
Maximum reverse current at working peak reverse voltage <sup>(1)</sup>		$T_J = 25\text{ }^\circ\text{C}$ $T_J = 125\text{ }^\circ\text{C}$	$I_R$	4.5 6.0	$\mu\text{A}$ mA

Note:

(1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle

<b>THERMAL CHARACTERISTICS</b> ( $T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance	$R_{\theta JC}$	2.7	5.8	2.7	$^\circ\text{C/W}$

<b>ORDERING INFORMATION</b> (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AC	MBR10H100-E3/45	1.80	45	50/tube	Tube
ITO-220AC	MBRF10H100-E3/45	1.94	45	50/tube	Tube
TO-263AB	MBRB10H100-E3/45	1.33	45	50/tube	Tube
TO-263AB	MBRB10H100-E3/81	1.33	81	800/reel	Tape and reel
TO-220AC	MBR10H100HE3/45 <sup>(1)</sup>	1.80	45	50/tube	Tube
ITO-220AC	MBRF10H100HE3/45 <sup>(1)</sup>	1.94	45	50/tube	Tube
TO-263AB	MBRB10H100HE3/45 <sup>(1)</sup>	1.33	45	50/tube	Tube
TO-263AB	MBRB10H100HE3/81 <sup>(1)</sup>	1.33	81	800/reel	Tape and reel

Note:

(1) Automotive grade AEC Q101 qualified

## RATINGS AND CHARACTERISTICS CURVES

( $T_A = 25\text{ }^\circ\text{C}$  unless otherwise noted)

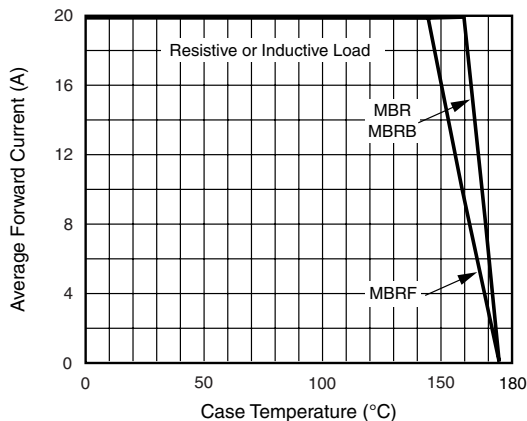


Figure 1. Forward Current Derating Curve

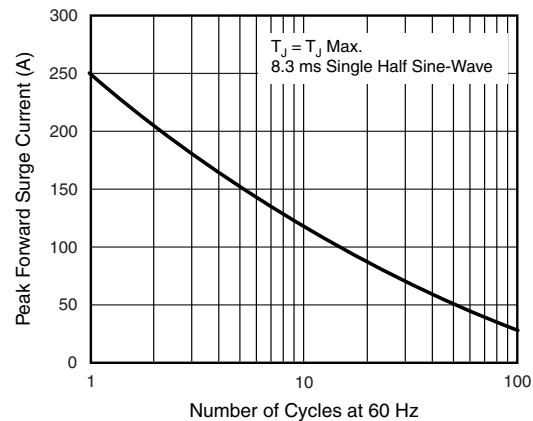


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current

# MBR(F,B)10H90 & MBR(F,B)10H100

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## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

